ASMT-Mx00
High Power LED Light Source
Prelim Datasheet

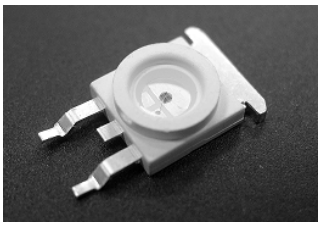
Description

High Power LED Light Source is a high performance energy efficient device which can handle high thermal and high driving current. The exposed pad design has excellent heat transfer from the package to the motherboard.

The low profile package design is suitable for a wide variety of applications especially where height is a constraint.

The package is compatible with SMT reflow soldering process and manual soldering. This will give more freedom and flexibility to the light source designer.

Component Image



Features

- Available in White, Blue, Green color.
- Energy efficient
- Exposed pad for excellent heat transfer.
- Suitable for SMT process.
- High current operation.
- Long operation life.
- Wide viewing angle.
- Silicone encapsulation

Specifications

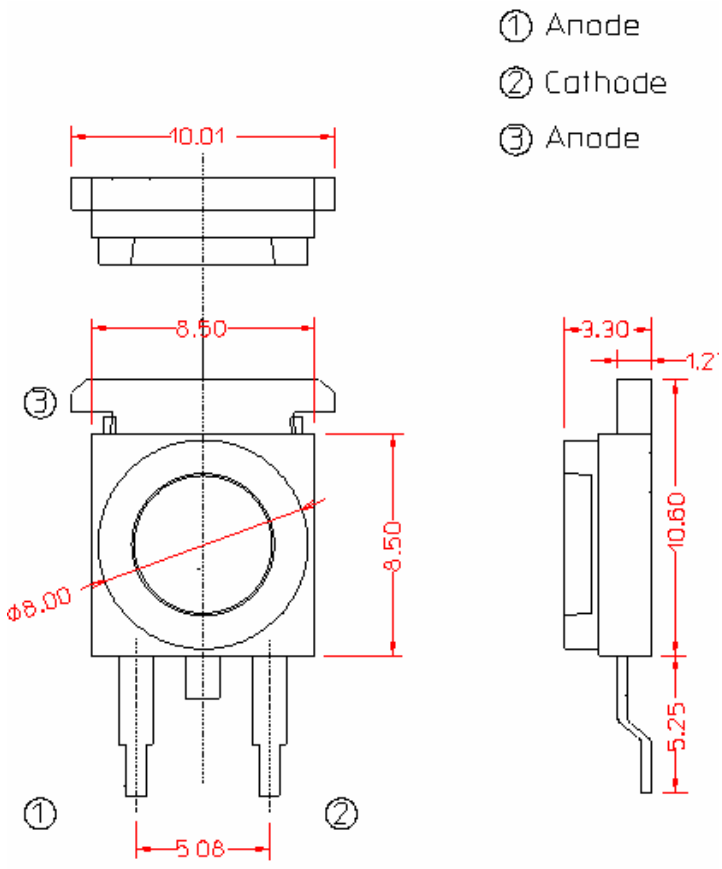
- InGaN Technology
- 3.6V, 350 mA (Typ.)
- 120 viewing angle
- ESD sensitive Class 2

Applications

- Portable (flash light, bicycle head light)
- Reading light
- Architectural lighting
- Garden lighting.
- Decorative lighting.

CAUTION: ASMT-Mx00-xxxxx LEDs are Class 2 ESD sensitive. Please observe appropriate precautions during handling and processing. Refer to Avago Application Note AN-1142 for additional details.

Package Dimensions



Notes:

1. All Dimensions in millimeters.
2. Tolerance is ±0.1mm unless otherwise specified.

Device Selection Guide at Junction Temperature Tj = 25°C

Color	Part Number	Min. Flux (lm)	Typ. Flux [1] (lm)	Max. Flux (lm)	Test Current (mA)	Dice Technology
Green	ASMT-MG00-NGJ00	25.5	40	73.0	350	InGaN
Blue	ASMT-MB00-NAE00	5.5	10	19.5	350	InGaN
White	ASMT-MW00-NFI00	19.5	35	56.0	350	InGaN

Notes:

1. Φ_V is the total luminous flux output as measured with an integrating sphere at mono pulse condition.
2. Flux tolerance is +/-15 %

Absolute Maximum Ratings at T_A = 25°C

Parameter	ASMT-Mx00	Units
DC Forward Current	350	mA
Peak Pulsing Current [1]	500	mA
Power Dissipation	1400	mW
LED Junction Temperature	110	°C
Operating Temperature Range	-40 to +85	°C
Storage Temperature Range	-40 to +100	°C
Soldering Temperature	Refer to figure 6	

Note:

1. Pulse condition duty factor = 10%, Frequency = 1kHz.

Optical Characteristics (T_A = 25 °C)

Part Number	Color	Peak Wavelength λ_{PEAK} (nm)	Dominant Wavelength λ_D [1] (nm)	Viewing Angle $2\theta_{½}$ [2] (Degrees)	Luminous Efficacy, η_v[3] (lm/W)	Luminous Efficiency (lm/W)
		Typ.	Typ.	Typ.	Typ.	Typ
ASMT- MG00	Green	519	525	120	460	32
ASMT- MB00	Blue	460	467	120	58	8

Part Number	Color	Typical Chromaticity Coordinates [4]		Viewing Angle $2\theta_{½}$ [2] (Degrees)	Luminous Efficacy, η_v[3] (lm/W)	Luminous Efficiency (lm/W)
		x	y	Typ.	Typ	Typ
ASMT-MW00	White	0.32	0.31	120	300	28

Notes:

1. The dominant wavelength, λ_D, is derived from the CIE Chromaticity Diagram and represents the color of the device.
2. θ½ is the off-axis angle where the luminous intensity is ½ the peak intensity.
3. Radiant intensity, I_e in watts/steradian, may be calculated from the equation $I_e = I_v/\eta_v$, where I_v is the luminous intensity in candelas and η_v is the luminous efficacy in lumens/watt.
4. The typical chromaticity coordinate is the overall package x y coordinates.

Electrical Characteristic (T_A = 25°C)

Part Number	Forward Voltage V_F (Volts) @ I_F = 350mA	Reverse Voltage V_R	Thermal Resistance Rjp (°C/W)
	Typ		Typ.
InGaN	3.6	Note	10

Note:
1. Not designed for reverse bias operation.

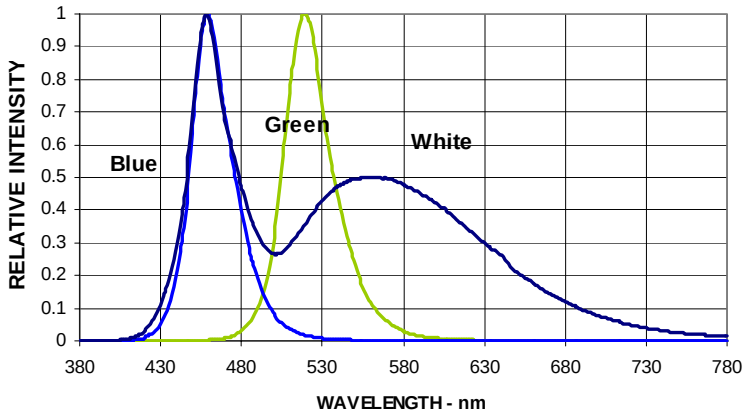


Figure 1: Relative Intensity vs. Wavelength

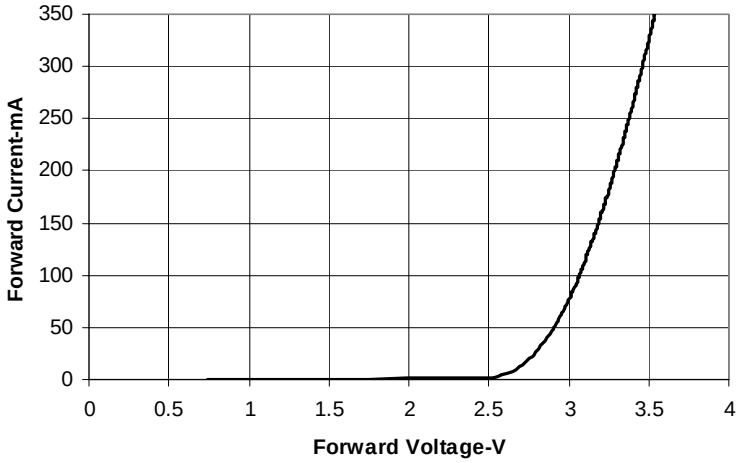


Figure 2: Forward Current vs Forward Voltage

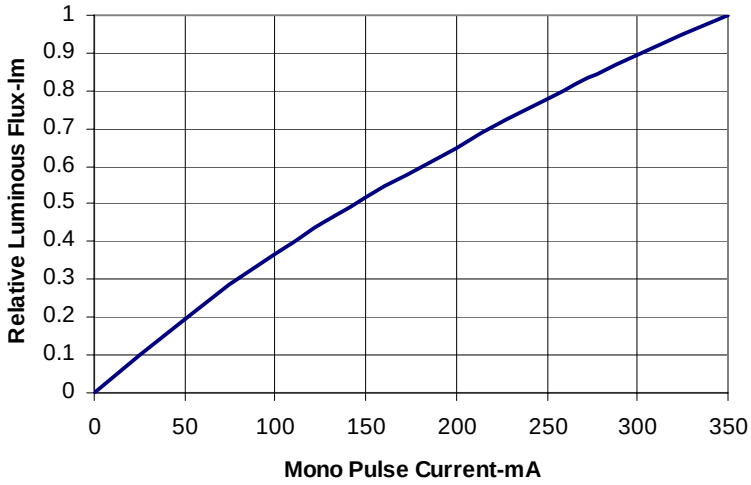


Figure 3: Relative Luminous Flux vs. Mono Pulse Current

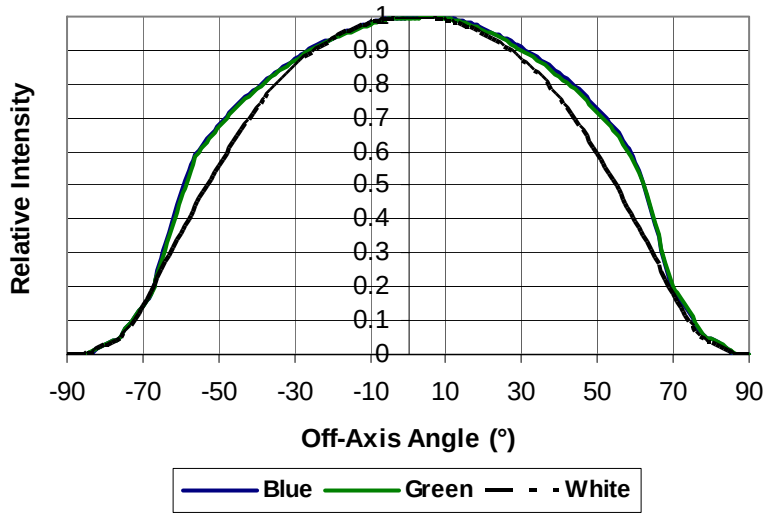


Figure 4. Radiation Pattern

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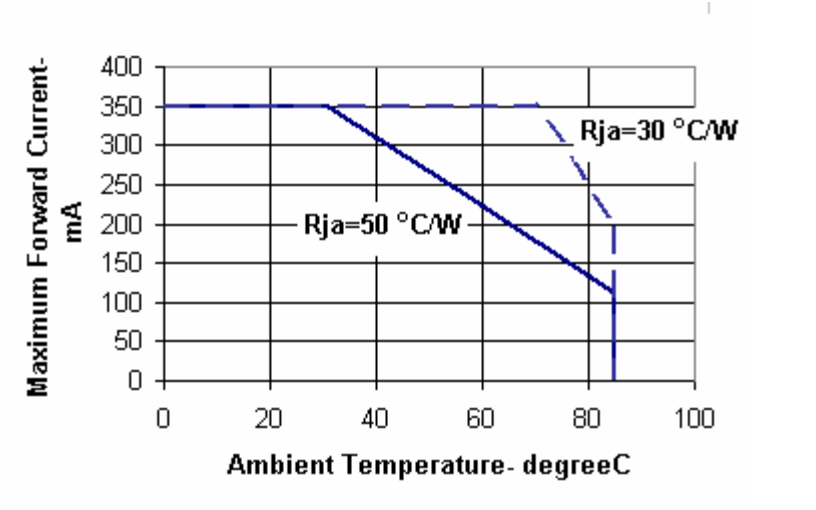

Figure 5. Maximum Forward Current vs. Ambient Temperature Derated Based on T_JMAX = 110°C, $R\theta_{JA}$ = 30°C/W / $R\theta_{JA}$ = 50°C/W

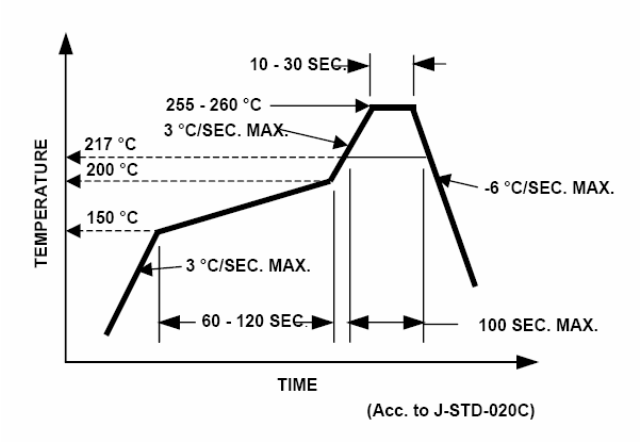

Figure 6. Maximum Forward Current vs. Ambient Temperature

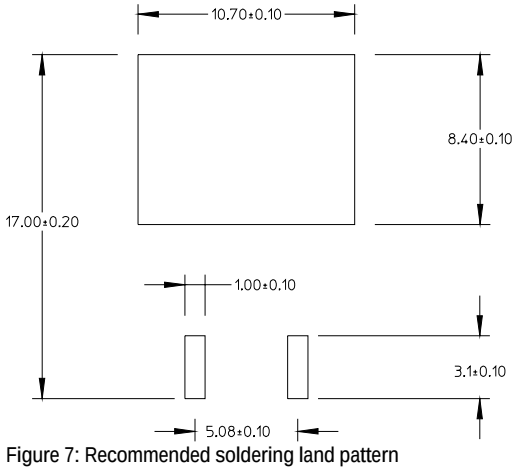

Figure 7: Recommended soldering land pattern

Illuminance Flux Bin Limit (For reference only)

Bin	Illuminance Flux (lm) at 350mA	
	Min	Max
A	5.5	7.0
B	7.0	9.0
C	9.0	11.5
D	11.5	15.0
E	15.0	19.5
F	19.5	25.5
G	25.5	33.0
H	33.0	43.0
I	43.0	56.0
J	56.0	73.0

Tolerance for each bin limits is +/-15 %

Color Bin Limits

Blue	Min (nm)	Max (nm)
A	460.0	465.0
B	465.0	470.0
C	470.0	475.0
D	475.0	480.0

Green	Min (nm)	Max (nm)
A	515.0	520.0
B	520.0	525.0
C	525.0	530.0
D	530.0	535.0

Tolerance = ±1nm

White	Color Limits (Chromaticity Coordinates)				
Bin A	X	0.367	0.362	0.329	0.329
	Y	0.400	0.372	0.345	0.369
Bin B	X	0.362	0.356	0.329	0.329
	Y	0.372	0.330	0.302	0.345
Bin C	X	0.329	0.329	0.305	0.301
	Y	0.369	0.345	0.322	0.342
Bin D	X	0.329	0.329	0.311	0.305
	Y	0.345	0.302	0.285	0.322
Bin E	X	0.303	0.307	0.283	0.274
	Y	0.333	0.311	0.284	0.301
Bin F	X	0.307	0.311	0.290	0.283
	Y	0.311	0.285	0.265	0.284

Tolerances +/- 0.02

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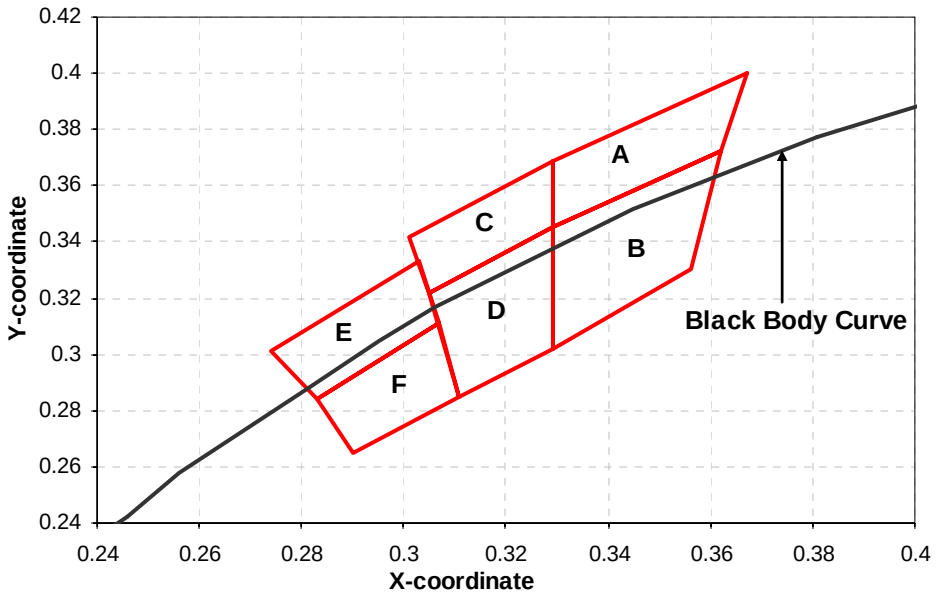

Handling Precaution

The encapsulation material of the product is made of silicone for better reliability of the product. As silicone is a soft material, please do not press on the silicone or poke a sharp object onto the silicone. These might damage the product and cause premature failure. During assembly or handling, the unit should be held on the body (white epoxy).

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